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3.3 V LVDS 1-Bit, High-Speed Differential Driver

FIN1001

Description

This single driver is designed for high-speed interconnects utilizing Low Voltage Differential Signaling (LVDS) technology. The driver translates LVTTL levels to LVDS levels with a typical differential output swing of 350 mV which provides low EMI at ultra low power dissipation even at high frequencies. This device is ideal for high-speed transfer of clock or data. The FIN1001 can be paired with its companion receiver, the FIN1002, or with any other LVDS receiver.

Features

- Greater than 600 Mbs Data Rate
- 3.3 V Power Supply Operation
- 0.5 ns Maximum Pulse Skew
- 1.5 ns Maximum Propagation Delay
- Low Power Dissipation
- Power–Off Protection
- Meets or Exceeds TIA/EIA-644 LVDS Standard
- Flow-through Pin-out Simplifies PCB Layout
- 5-Lead SOT23 Package Saves Space
- This is a Pb–Free and Halide Free Device

PIN DEFINITIONS

Pin No.	Name	Description
1	V _{CC}	Power Supply
2	GND	Ground
3	Dout-	Inverting LVDS Driver Output
4	Dout+	Non-inverting LVDS Driver Output
5	Din	LVTTL Data Input

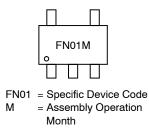
FUNCTION TABLE

Inputs	Outputs			
D _{IN}	D _{OUT+}	D _{OUT-}		
LOW	LOW	HIGH		
HIGH	HIGH	LOW		

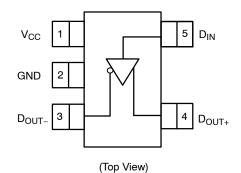


SOT-23, 5 Lead CASE 527AH

MARKING DIAGRAMS



CONNECTION DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Min.	Max.	Unit
V _{CC}	Supply Voltage			-0.5	4.6	V
D _{IN}	DC Input Voltage			-0.5	6.0	V
D _{OUT}	DC Output Voltage			-0.5	4.6	V
I _{OSD}	Driver Short Circuit Current		Conti	nuous		
Ι _Ο	Output Current			-	16	mA
T _{STG}	Storage Temperature Range			-65	+150	°C
TJ	Maximum Junction Tempe	Maximum Junction Temperature		-	+150	°C
ΤL	Lead Temperature, Solde	Lead Temperature, Soldering, 10 Seconds		-	+260	°C
ESD	Electrostatic Discharge	Human Body Model		-	7500	V
		Machine Model		-	400	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V _{CC}	Supply Voltage	3.0	3.6	V
V _{IN}	Input Voltage	0	Vcc	V
T _A	Operating Temperature	-40	+125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (Note 1)

All min and max values are guaranteed at $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise specified. All typical values are at $T_A = 25^{\circ}C$ and with $V_{CC} = 3.3$ V, unless otherwise specified.

Symbol	Parameter		Conditions	Min	Тур	Max	Unit
V _{OD}	Output Differential Voltage	$R_L = 100 \Omega$,	$T_A = -40^{\circ}C$ to $85^{\circ}C$	250	350	450	mV
		See Figure 1	$T_A = -40^{\circ}C$ to $125^{\circ}C$	230	350	450	mV
ΔV_{OD}	VOD Magnitude Change from Differential Low-to-High		$T_A = -40^\circ$ to 125°C	-	-	25	mV
V _{OS}	Offset Voltage			1.125	1.25	1.375	V
ΔV_{OS}	Offset Magnitude Change from Differential Low-to-High			-	-	25	mV
I _{OFF}	Power-Off Output Current	$V_{CC} = 0 V, V_{OI}$	T = 0 V or 3.6 V	-	-	±20	μA
I _{OS}	Short Circuit Output Current	V _{OUT} = 0 V		-	-5.5	-8	mA
		V _{OD} = 0 V		-	±4	±8	1
I _{I(OFF)}	Power-OFF Input Current	$V_{CC} = 0 \text{ V}, \text{ V}_{IN} = 0 \text{ V} \text{ or } 3.6 \text{ V}$		-	-	±20	μA
V _{IH}	Input HIGH Voltage			2.0	-	VCC	V
V _{IL}	Input LOW Voltage			GND	-	0.8	V
I _{IN}	Input Current	V _{IN} = 0 V or V _{CC}		-	-	±20	μA
I _{I(OFF)}	Power-Off Input Current	V_{CC} = 0 V, V_{IN}	= 0 V or 3.6 V	-	-	±20	μA
V _{IK}	Input Clamp Voltage	I _{IK} = –18 mA		-1.5	-0.8	-	V
I _{CC}	Power Supply Current	No Load, $V_{IN} = 0$ V or V_{CC}		-	4.5	8	mA
		$R_L = 100 \Omega$, $V_{IN} = 0 V$ or V_{CC}		-	6.5	10	1
C _{IN}	Input Capacitance	V _{CC} = 3.3 V		-	3.2	-	pF
COUT	Output Capacitance	$V_{CC} = 0 V$		_	3.3	_	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Not production tested across the full temperature range.

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AC ELECTRICAL CHARACTERISTICS

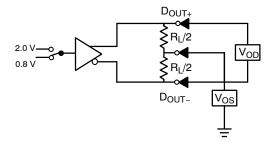
All min and max values are guaranteed at $T_A = -40$ to $+85^{\circ}C$.

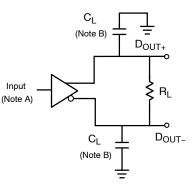
All typical values are at $T_A=25^\circ C$ and with $V_{CC}=3.3$ V, unless otherwise specified. $R_L=100~\Omega,~C_L=5~pF.$ See Figure 2 and Figure 3.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
t _{PLHD}	Propagation Delay	LOW to HIGH	0.50	0.98	1.50	ns
t _{PHLD}	Propagation Delay	HIGH to LOW	0.50	0.93	1.50	ns
t _{TLHD}	Differential Output Rise Time	20% to 80%	0.4	0.5	1.0	ns
t _{THLD}	Output Fall Time	80% to 20%	0.4	0.5	1.0	ns
t _{SK(p)}	Pulse Skew	t _{PLH} - t _{PHL}	-	0.05	0.5	ns
t _{SK(PP)}	Part-to-Part Skew (Note 2)		-	-	1.0	ns

 t_{SK(PP)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices switching in the same direction (either LOW-to-HIGH or HIGH-to-LOW) when both devices operate with the same supply voltage, same temperature, and have identical test circuits

TEST DIAGRAMS





Note A: All input pulses have frequency = 10 Mhz, t_R or t_F = 2 ns

Note B: C_{L} includes all probe and fixture capacitances

Figure 1. Differential Driver DC Test Circuit

Figure 2. Differential Driver Propagation Delay and Transition Time Test Circuit

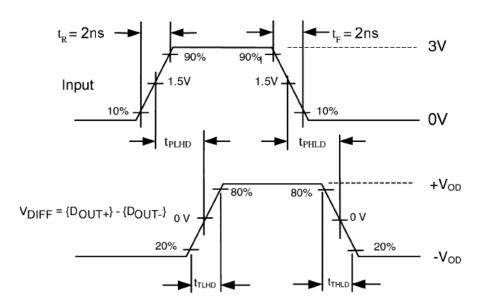
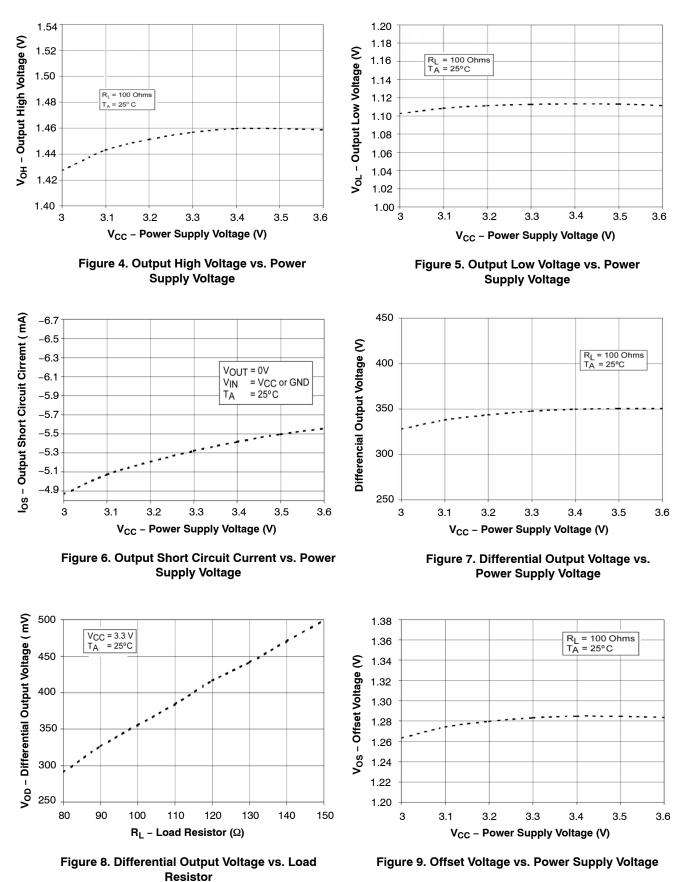
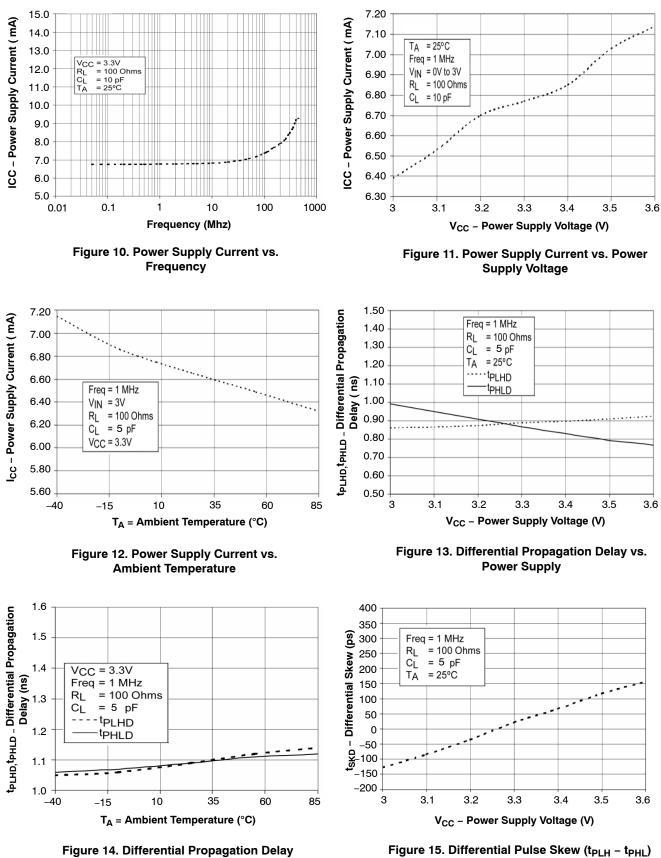


Figure 3. AC Waveforms



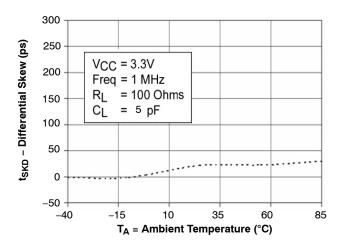
TYPICAL PERFORMANCE CHARACTERISTICS

TYPICAL PERFORMANCE CHARACTERISTICS

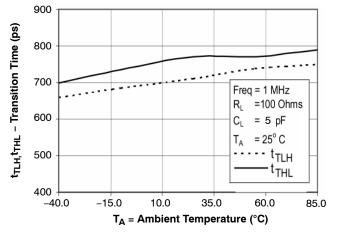


vs. Ambient Temperature











ORDERING INFORMATION

Part Number	Operating Temperature Range	Package	Shipping [†]
FIN1001M5X	–40°C – +125°C	5-Lead SOT23, JEDEC MO-178, 1.6 mm (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

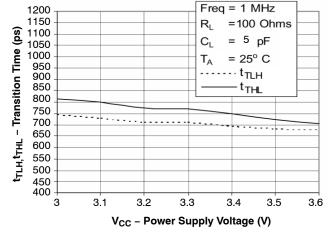
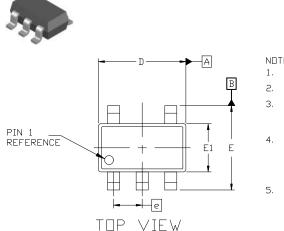


Figure 17. Transition Time vs. Power Supply Voltage



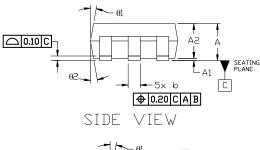


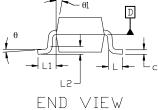


DATE 09 JUN 2021

NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.





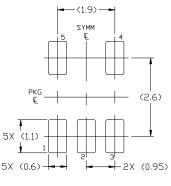
GENERIC **MARKING DIAGRAM***



XXX = Specific Device Code = Date Code М

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS				
DIM	MIN.	NDM.	MAX.		
А	0.90	—	1.45		
A1	0.00	_	0.15		
A2	0.90	1.15	1.30		
b	0.30	—	0.50		
С	0.08	—	0.22		
D	2.90 BSC				
E	2.80 BSC				
E1	1.60 BSC				
е	0.95 BSC				
L	0.30	0.45	0.60		
L1	0.60 REF				
L2	0.25 REF				
θ	0*	4°	8*		
θ1	0°	10°	15°		
θ2	0*	10°	15°		



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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